HVC317B

Variable Capacitance Diode for tuner

HITACHI

ADE-208-445(Z)
Rev 0
Apl. 1996

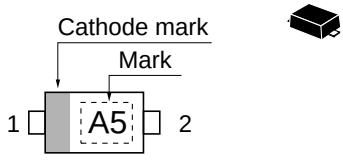
Features

- High capacitance ratio. (n =13.0 min)
- Ultra small Flat Package (UFP) is suitable for surface mount design.

Ordering Information

Type No.	Laser Mark	Package Code
HVC317B	A5	UFP

Outline



1. Cathode
2. Anode

Hitachi semiconductor

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Value	Unit
Reverse voltage	V_R	35	V
Junction temperature	Tj	125	°C
Storage temperature	Tstg	–55 to +125	°C

Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse current	I_{R1}	—	—	10	nA	V_R = 30V
	I_{R2}	—	—	100		V_R = 30V, Ta = 60 °C
Capacitance	C_1	9.00	—	11.5	pF	V_R = 1V, f = 1 MHz
	C_{25}	0.60	—	0.80		V_R = 25V, f = 1 MHz
Capacitance ratio	n	13.0	—	—	—	C_1/ C_{25}
Series resistance	r_s	—	—	1.6	Ω	V_R = 5V, f = 470 MHz
Matching error	ΔC/C*1	—	—	6.0	%	V_R = 1 to 25V, f = 1 MHz

Note: 1. C.C system (Continuous Connected taping system) enable to make any 10 pcs of ΔC/C continuous in a reel , expect extention to another group.
Calculate Matching Error,

$$\Delta C/C = \frac{(Cmax-Cmin)}{Cmin} \times 100\ (\%)$$

Main Characteristic

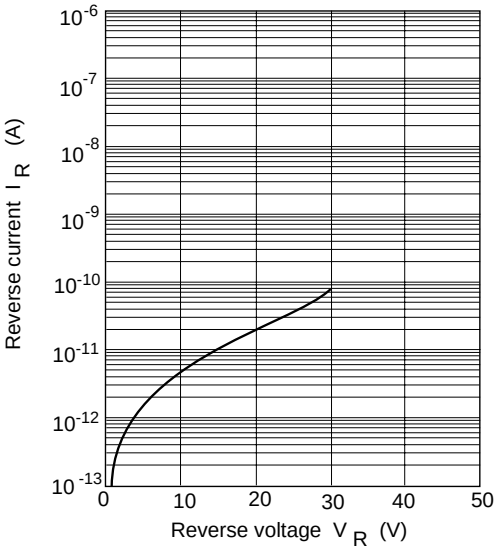


Fig.1 Reverse current Vs. Reverse voltage

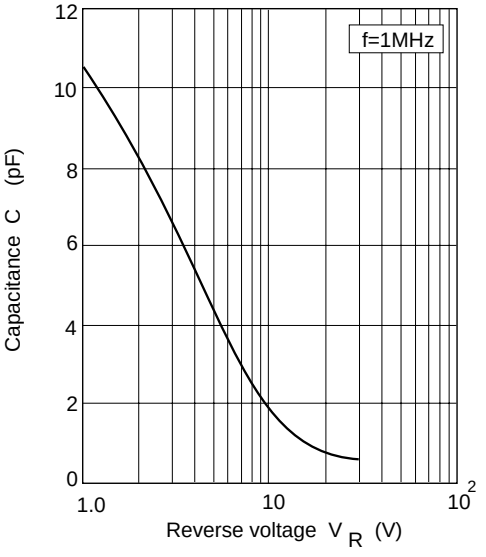


Fig.2 Capacitance Vs. Reverse voltage

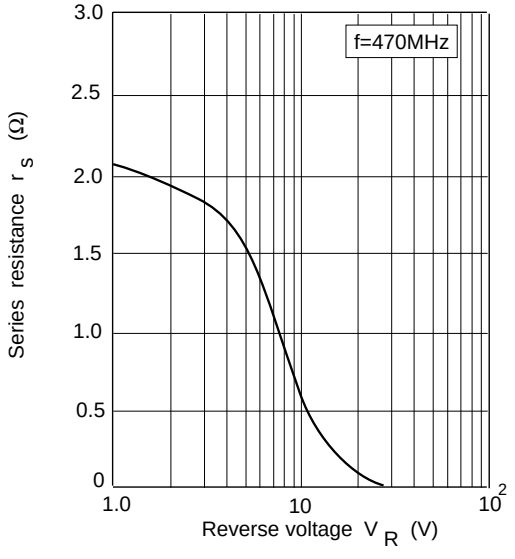


Fig.3 Series resistance Vs. Reverse voltage

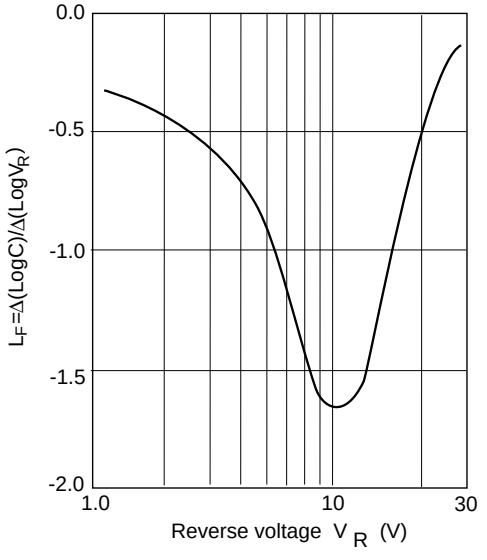
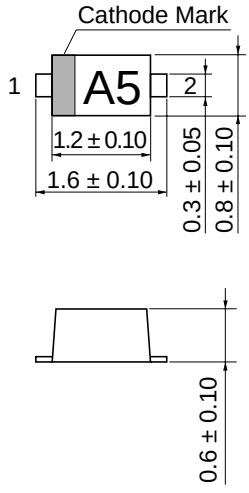


Fig.4 Linearity factor Vs. Reverse voltage

Package Dimensions

Unit : mm





1. Cathode
2. Anode

Hitachi Code	*UFP*
JEDEC Code	—
EIAJ Code	SC-79
Weight(g)	0.0016

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